
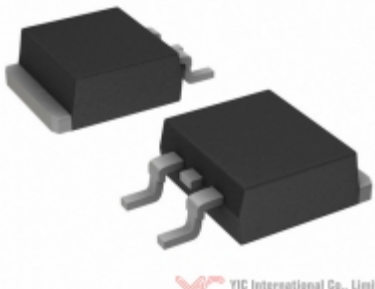








	<h2 style="color: #E67E22;">FQB24N08TM</h2>
	<p>Hersteller-Teilenummer: FQB24N08TM</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 80V 24A D2PAK</p> <p>Datenblätter:  FQB24N08TM.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 2400 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQB24N08TM
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 80V 24A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	2400 pcs Stock
detaillierte Beschreibung	N-Channel 80V 24A (Tc) 3.75W (Ta), 75W (Tc) Surface
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.75W (Ta), 75W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	80V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	24A (Tc)
Rds On (Max) @ Id, Vgs	60 mOhm @ 12A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	25nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	750pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)



















































FQB24N08TM ist neu im Original, Suche FQB24N08TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB24N08TM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB24N08TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB22P10TM-F085 AMI Semiconductor / ON Semiconductor MOSFET P-CH 100V 22A D2PAK</p>	 <p>FQB25N33TM-F085 AMI Semiconductor / ON Semiconductor MOSFET N-CH 330V 25A D2PAK</p>	 <p>FQB25N33TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 330V 25A D2PAK</p>	 <p>FQB25N33TM Fairchild/ON Semiconductor MOSFET N-CH 330V 25A D2PAK</p>
 <p>FQB24N08TM Fairchild/ON Semiconductor MOSFET N-CH 80V 24A D2PAK</p>	 <p>FQB24N08 FSC FSC TO-263</p>	 <p>FQB22P10TM AMI Semiconductor / ON Semiconductor MOSFET P-CH 100V 22A D2PAK</p>	 <p>FQB25N33 FAIRCHI FQB25N33 FAIRCHI</p>

heiße Teile

Mehr

Contact us: Info@Y-IC.com

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